

Technical Data Data Sheet N1111, Rev. A

SBRF2045 SCHOTTKY RECTIFIER

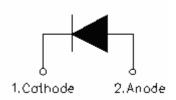
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

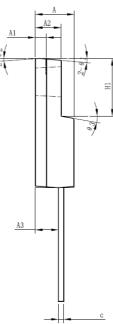
Features:

- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm



ah ah ah



	RAINI	TVD		
SYMBOL	MIN.	TYP.	MAX.	
A			4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
С	0.55	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е	- 2.55		-	
e1	- <u>2.55</u> - <u>5.10</u>		-	
H1	6.50 6.70		6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L2 L3	0.60	0.80	1.20 1.00	
L4	-	1.10	1.50	
ΦΡ1(上口)	3.30	3.50	3.70	
ΦΡ2(下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

ITO-220AC(HD)

Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 (86) 25-87123907 •
FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •

Green Products

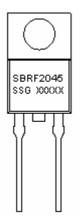


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Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0 Where XXXXX is YYWWL

SBR	= Device Type
F	= Package type
20	= Forward Current (20A)
45	= Reverse Voltage (45V)
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Ordering Information:

Device	Package	Shipping
SBRF2045	ITO-220AB	Elener / tube
	(Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	45	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle $@T_C = 105$ °C, rectangular wave form	20	А
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3ms, half sine pulse	252	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	V _{F1}	@ 20 A, Pulse, T _C = 25 °C	0.65	V
	V_{F2}	@ 20 A, Pulse, T _C = 125 °C	0.60	V
Max. Reverse Current (per leg) *	I _{R1}	$@V_R = rated V_R$ T _C = 25 °C	1.0	mA
	I _{R2}	$@V_R = rated V_R$ T _c = 125 °C	50.0	mA
Max. Junction Capacitance (per leg)	CT	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	900	pF
Repetitive peak reverse current	IRRM	tp = 2 μs square F= 1 kHz	1	A
Non-Repetitive Avalanche Energy	Eas	$T_J = 25$ °C, IAS = 2 A, L = 1mH	2	mJ
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs

* Pulse Width < 300 μ s, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature Range	ΤJ	-	-55 to +150	°C
Storage Temperature Range	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{ extsf{ heta}JC}$	DC operation	1.5	°C/W
Approximate Weight	wt	-	2.0	g
Case Style		ITO-220AB		

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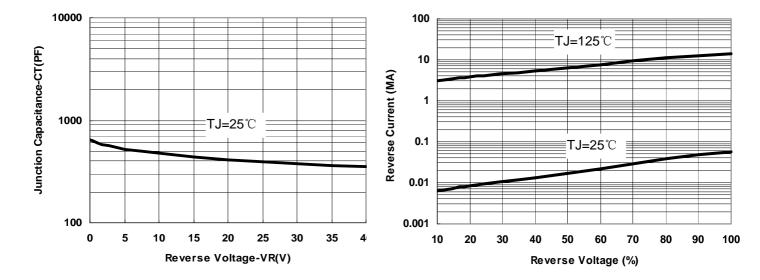




Fig.2-Typical Reverse Characteristics

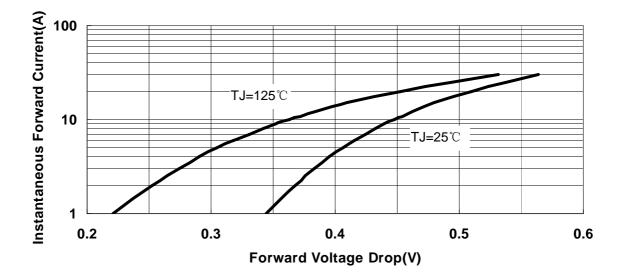


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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